National Semiconductor

DH0035/DH0035C PIN Diode Driver

General Description

The DH0035/DH0035C is a high speed digital driver designed to drive PIN diodes in RF modulators and switches. The device is used in conjunction with an input buffer such as the DM7830/DM8830 or DM5440/DM7440.

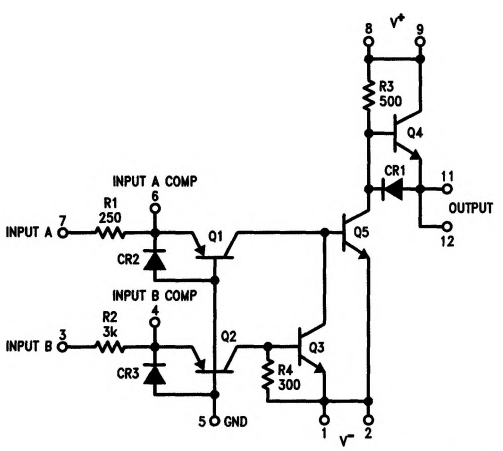
Features

- Large output voltage swing—30V
- Peak output current in excess of 1A
- Inputs TTL/DTL compatible
- Short propagation delay—10 ns
- High repetition rate—5 MHz

The DH0035/DH0035C is capable of driving a variety of PIN diode types including parallel, serial, anode grounded and cathode grounded. For additional information, see *AN-49 PIN Diode Drivers.*

The DH0035 is guaranteed over the temperature range −55°C to +125°C whereas the DH0035C is guaranteed from 0°C to +85°C.

Schematic and Connection Diagrams



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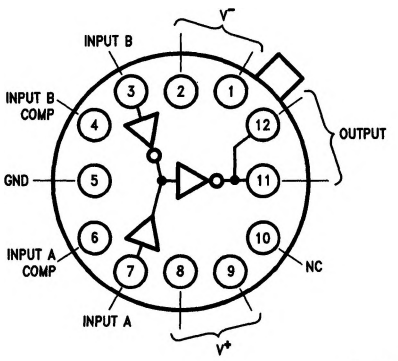
Metal Can Package



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Top View

Order Number DH0035G-MIL or DH0035CG
See NS Package Number G12B

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

V^- Supply Voltage Differential (Pin 5 to Pin 1 or 2)	40V
V^+ Supply Voltage Differential (Pin 1 or 2 to Pin 8 or 9)	30V
Input Current (Pin 3 or 7)	±75 mA
Peak Output Current	±1.0A
Power Dissipation (Note 3)	1.5W
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	
DH0035	−55°C to +125°C
DH0035C	0°C to +85°C
Lead Temperature (Soldering, 10 sec.)	300°C

Electrical Characteristics (Notes 1 and 2)

Parameter	Conditions	Limits			Units
		Min	Typ	Max	
Input Logic "1" Threshold	V_{OUT} = −8V, R_L = 100Ω		1.0	2.0	V
Input Logic "0" Threshold	V_{OUT} = +8V, R_L = 100Ω	0.4	0.6		V
Positive Output Swing	I_{OUT} = 100 mA	7.0	+8.0		V
Negative Output Swing	I_{OUT} = 100 mA		−8.0	−7.0	V
Positive Short Circuit Current	V_{IN} = 0V, R_L = 0Ω (Pulse Test, Duty Cycle ≤ 3%)	400	800		mA
Negative Short Circuit Current	V_{IN} = 1.5V, I_{IN} = 50 mA, R_L = 0Ω (Pulse Test, Duty Cycle ≤ 3%)	800	1000		mA
Turn-On Delay	V_{IN} = 1.5V, V_{OUT} = −3V		10	15	ns
Turn-Off Delay	V_{IN} = 1.5V, V_{OUT} = +3V		15	30	ns
On Supply Current	V_{IN} = 1.5V		45	60	mA

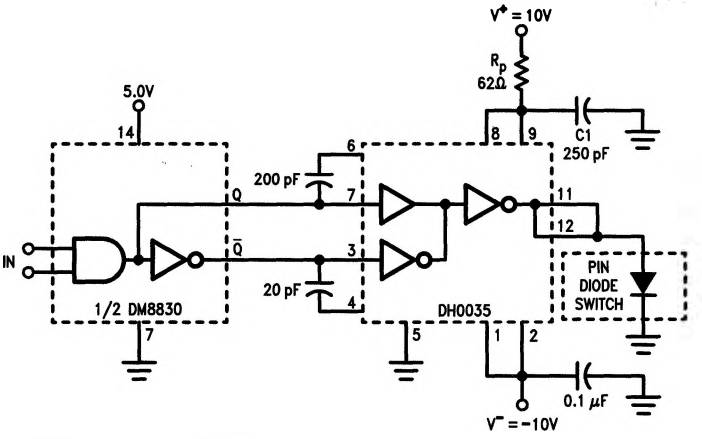
Note 1: Unless otherwise specified, these specifications apply for V^+ = 10.0V, V^- = − 10.0V, pin 5 grounded, over the temperature range −55°C to +125°C for the DH0035, and 0°C to +85°C for the DH0035C.

Note 2: All typical values are for T_A = 25°C.

Note 3: Derate linearly at 10 mW/°C for ambient temperatures above 25°C.

Typical Applications

Grounded Cathode Design



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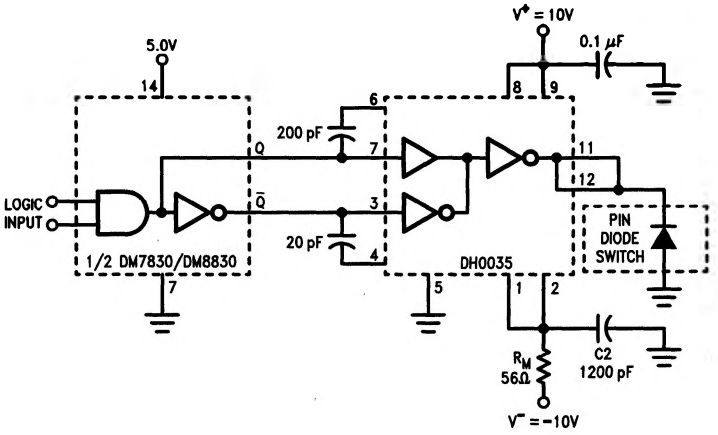
Note: Cathode grounded PIN diode: R_p = 62Ω limits diode forward current to 100 mA. Typical switching for HP33604A, RF turn-on 25 ns, turn-off 5 ns. C2 = 250 pF, R_p = 0Ω, C1 = 0.1F.

Typical Applications (Continued)

Grounded Anode Design



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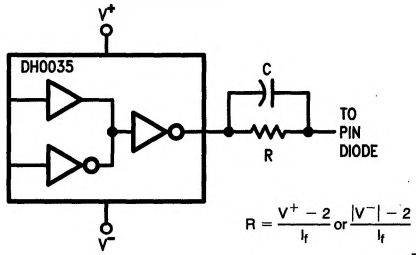
Note: Anode Grounded PIN diode: $R_M = 56\Omega$ limits diode forward current to 100 mA. Typical switching for HP33622A, RF turn-on 5 ns; turn-off 4 ns. C1 = 470 pF, C2 = 0.1 μF, $R_M = 0\Omega$.

Alternate Current Limiting



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